



**ELECTRONICS, INC.**  
 44 FARRAND STREET  
 BLOOMFIELD, NJ 07003  
 (973) 748-5089

## **NTE627 & NTE628 Silicon Rectifier Fast Recovery, Dual, Center Tap**

**Description:**

The NTE627 and NTE628 are dual, fast recovery silicon rectifiers in a TO220 type package designed for special applications such as DC power supplies, inverters, converters, ultrasonic systems, choppers and low RF interference.

**Features:**

- Low Forward Voltage
- High Switching Capability, Low Switching Noise
- High Voltage Capability
- Low Power Loss, High Reliability
- High Surge Capability
- Low Leakage Current

**Absolute Maximum Ratings:**

Peak Repetitive Reverse Voltage, $V_{RRM}$	
NTE627 .....	200V
NTE628 .....	600V
Working Peak Reverse Voltage, $V_{RWM}$	
NTE627 .....	200V
NTE628 .....	600V
DC Blocking Voltage, $V_R$	
NTE627 .....	200V
NTE628 .....	600V
RMS Reverse Voltage, $V_{R(RMS)}$	
NTE627 .....	140V
NTE628 .....	420V
Average Rectifier Forward Current (Rated $V_R$ , $T_C = +150^\circ\text{C}$ ), $I_{F(AV)}$	
Per Diode .....	6A
Total Device .....	12A
Non-Repetitive Peak Surge Current, $I_{FSM}$	
(8.3ms Single half Sine-Wave Superimposed on Rated Load) .....	120A
Operating Junction Temperature Range (Reverse Voltage Applied), $T_J$ .....	$-65^\circ$ to $+175^\circ\text{C}$
Storage Temperature Range (Reverse Voltage Applied), $T_{stg}$ .....	$-65^\circ$ to $+175^\circ\text{C}$

**Electrical Characteristics:**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Instantaneous Forward Voltage	$V_F$	$I_F = 6A$	-	-	1.3	V
Instantaneous Reverse Current	$I_R$	At Rated $V_R$ , $T_C = +25^\circ C$	-	-	10	$\mu A$
		At Rated $V_R$ , $T_C = +100^\circ C$	-	-	250	$\mu A$
Reverse Recovery Time	$t_{rr}$	$I_F = 0.5A, I_R = 1A, i_{rr} = 0.25A$	-	-	250	ns

